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ISSUE 12-09-22

SERIE : SPDT

PART NUMBER : R570E53100

## RF CHARACTERISTICS

Frequency range : **0 - 6 GHz**  
 Impedance : **50 Ohms**

Frequency (GHz)	DC - 3	3 - 6
VSWR max	<b>1.20</b>	<b>1.30</b>
Insertion loss max	<b>0.20 dB</b>	<b>0.30 dB</b>
Isolation min	<b>80 dB</b>	<b>70 dB</b>
Average power (*)	<b>240 W</b>	<b>170 W</b>

## ELECTRICAL CHARACTERISTICS

Actuator : **LATCHING**  
 Nominal current \*\* : **80 mA**  
 Actuator voltage (Vcc) : **28V (24 to 30V)**  
 Terminals : **solder pins (250°C max. / 30 sec.)**  
 Self cut-off time : **40 ms < CT < 120 ms**  
 TTL inputs (E) - High level : **2.2 to 5.5 V / 800µA at 5.5 V**  
 - Low level : **0 to 0.8 V / 20µA at 0.8 V**

## MECHANICAL CHARACTERISTICS

Connectors : **QMA female per MIL-C 39012**  
 Life : **10 million cycles**  
 Switching Time\*\*\* : **< 10 ms**  
 Construction : **Splashproof**  
 Weight : **< 45 g**

## ENVIRONMENTAL CHARACTERISTICS

Operating temperature range : **-40°C to +85°C**  
 Storage temperature range : **-55°C to +85°C**

(\* Average power at 25°C per RF Path)

(\*\* At 25° C ±10%)

(\*\*\* Nominal voltage ; 25° C)



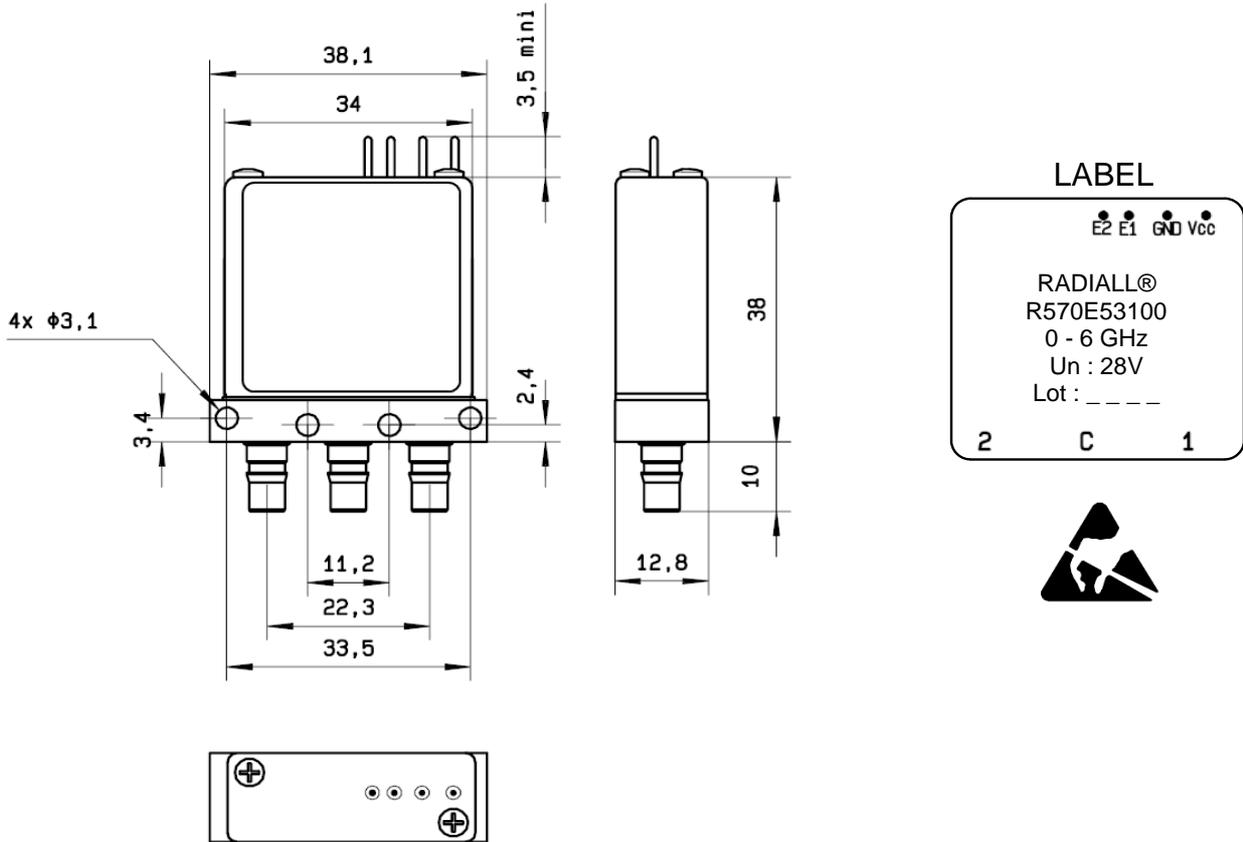
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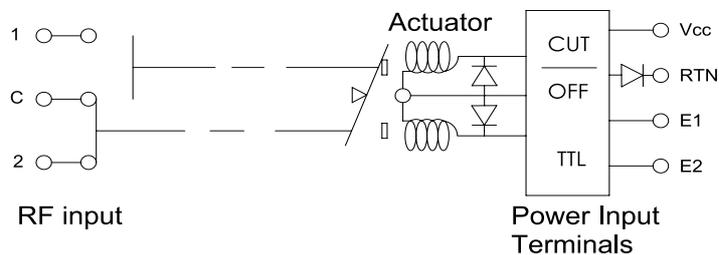
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DRAWING



General tolerances : ±0,5 mm [0,02 in]

SCHEMATIC DIAGRAM



TTL input	RF Continuity
E1=1 / E2=0	C ↔ 1
E1=0 / E2=1	C ↔ 2
E1=0 / E2=0	Memory
E1=1 / E2=1	Forbidden